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(Materials Research Society Symposia Proceedings, 1989) Vol. 144, p. 565. **Concise Encyclopedia of Semiconducting Materials & Related - Google Books Result** Advances in Materials, Processing and Devices in III-V Compound Semiconductors: Volume 144 juz od 206,87 zł - od 206,87 zł, porównanie cen w 1 sklepie. **Materials Science in Semiconductor Processing Vol 9, Iss 13** Advances in Materials, Processing and Devices in III-V Compound Semiconductors: Volume 144 (MRS Proceedings) at - ISBN 10: 1107410762 **Advances in Materials, Processing and Devices in III-V Compound** Jokerst, N. M., Hybrid Integrated Optoelectronics: Thin Film Devices Bonded to Host . Palit, S Royal, M Jokerst, N Kirch, J Mawst, L, Integration of a thin film III-V NM, Heterogeneous integration of thin-film compound semiconductor lasers Materials Research Society Symposium - Proceedings, vol 441 (1997), pp. **SUBHASH MAHAJAN School of Materials 8824 S. 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